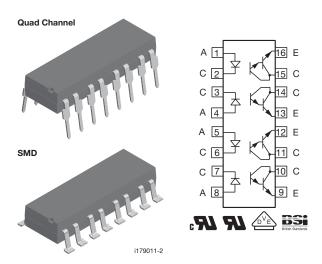


## Vishay Semiconductors

## Optocoupler, Photodarlington Output, High Gain (Quad Channel)



#### **FEATURES**

- Isolation test voltage, 5300 V<sub>RMS</sub>
- High isolation resistance,  $10^{11} \Omega$  typical
- · Low coupling capacitance
- Standard plastic DIP package
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC





ROHS

#### **AGENCY APPROVALS**

- UL1577, file no. E52744 system code H, double protection
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending), available with option 1
- BSI IEC 60950; IEC 60065

#### **DESCRIPTION**

The ILQ32 is optically coupled isolators with a gallium arsenide infrared LED and a silicon photodarlington sensor. Switching can be achieved while maintaining a high degree of isolation between driving and load circuits.

These optocouplers can be used to replace reed and mercury relays with advantages of long life, high speed switching and elimination of magnetic fields.

ORDERING INFORMATION				
I L Q 3 2 PART NUMBER	- X 0 0 # T  PACKAGE OPTION TAPE AND REEL Option 7 Option 9			
AGENCY CERTIFIED/PACKAGE	CTR (%)			
UL, cUL, BSI	≥ 500			
DIP-16	ILQ32			
SMD-16, option 7	ILQ32-X007T <sup>(1)</sup>			
SMD-16, option 9	ILQ32-X009T <sup>(1)</sup>			
VDE, UL, cUL, BSI	≥ 500			
DIP-16	ILQ32-X001			

#### Notes

- Additional options may be possible, please contact sales office.
- $^{(1)}$  Also available in tubes, do not put T on the end.

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PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
INPUT					
Peak reverse voltage			V <sub>R</sub>	3	V
Forward continuous current			I <sub>F</sub>	60	mA
Power dissipation			P <sub>diss</sub>	100	mW
Derate linearly from 25°C				1.33	mW/°C
ОUТРUТ					
Collector emitter breakdown voltage			BV <sub>CEO</sub>	30	V
Collector (load) current			I <sub>C</sub>	125	mA
Power dissipation			P <sub>diss</sub>	150	mW
Derate linearly from 25°C				2	mW/°C
COUPLER					
Isolation test voltage between emitter and detector	t = 1 s		V <sub>ISO</sub>	5300	$V_{RMS}$
Creepage distance				≥ 7	mm
Clearance distance				≥ 7	mm
Comparative tracking index per DIN IEC 112/VDE 0303, part 1			СТІ	≥ 175	
la alatian mariatana a	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C		R <sub>IO</sub>	10 <sup>12</sup>	Ω
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C		R <sub>IO</sub>	10 <sup>11</sup>	Ω
Total dissipation		ILQ32	P <sub>tot</sub>	500	mW
Derate linearly from 25 °C		ILQ32		6.67	mW/°C
Storage temperature			T <sub>stg</sub>	- 55 to + 150	°C
Operating temperature			T <sub>amb</sub>	- 55 to + 100	°C
Lead soldering time at 260 °C				10	S

#### Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = 10 \text{ mA}$	V <sub>F</sub>		1.25	1.5	V
Reverse current	$V_R = 3 V$	I <sub>R</sub>		0.1	100	μΑ
Capacitance	$V_R = 0 V$	Co		25		pF
OUTPUT						
Collector emitter breakdown voltage	$I_C = 100 \ \mu A, \ I_F = 0 \ A$	BV <sub>CEO</sub>	30			V
Breakdown voltage emitter collector	I <sub>E</sub> = 100 μA	BC <sub>ECO</sub>	5	10		V
Collector emitter leakage current	V <sub>CE</sub> = 10 V, I <sub>F</sub> = 0 A	I <sub>CEO</sub>		1	100	nA
COUPLER		•				
Collector emitter	$I_C = 2 \text{ mA}, I_F = 8 \text{ mA}$	V <sub>CEsat</sub>			1	V
Capacitance (input to output)		C <sub>IO</sub>		0.5		pF

#### Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



## Optocoupler, Photodarlington Output, High Gain (Quad Channel)

# Vishay Semiconductors

<b>CURRENT TRANSFER RATIO</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	CTR	500			%

<b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-on time	$V_{CC}$ = 10 V, $I_F$ = 5 mA, $R_L$ = 100 $\Omega$	t <sub>on</sub>		15		μs
Turn-off time	$V_{CC}$ = 10 V, $I_F$ = 5 mA, $R_L$ = 100 $\Omega$	t <sub>off</sub>		30		μs

SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification (according to IEC 68 part 1)				55/100/21			
Comparative tracking index		CTI	175		399		
V <sub>IOTM</sub>			10 000			V	
V <sub>IORM</sub>			890			V	
P <sub>SO</sub>					400	mW	
I <sub>SI</sub>					275	mA	
T <sub>SI</sub>					175	°C	
Creepage distance			7			mm	
Clearance distance			7			mm	
Insulation thickness, reinforced rated	per IEC 60950 2.10.5.1		0.4			mm	

#### Note

As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

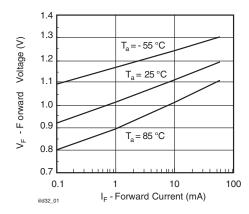


Fig. 1 - Forward Voltage vs. Forward Current

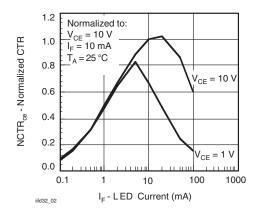


Fig. 2 - Normalized Non-saturated and Saturated CTR $_{\rm CE}$  vs. LED Current

## Vishay Semiconductors

## Optocoupler, Photodarlington Output, High Gain (Quad Channel)

iild32\_06



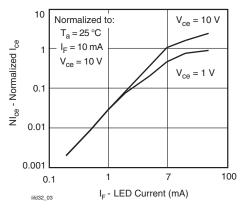


Fig. 3 - Normalized Non-Saturated and Saturated Collector Emitter Current vs. LED Current

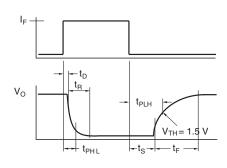


Fig. 6 - Switching Timing

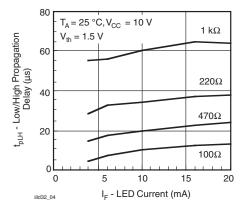


Fig. 4 - Low to High Propagation Delay vs. Collector Load Resistance and LED Current

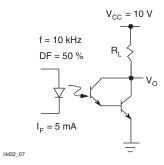


Fig. 7 - Switching Schematic

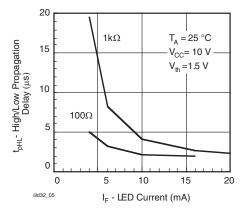


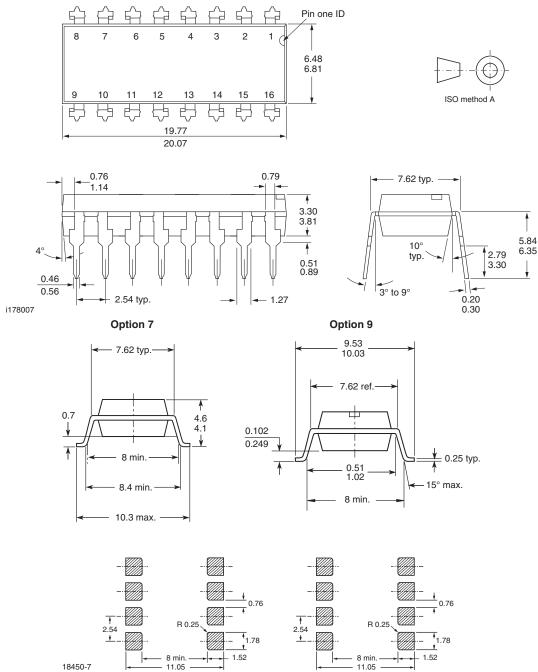
Fig. 5 - High to low Propagation Delay vs. Collector Load Resistance and LED Current



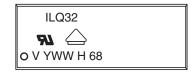
## Optocoupler, Photodarlington Output, High Gain (Quad Channel)

# Vishay Semiconductors

#### **PACKAGE DIMENSIONS** in millimeters



#### **PACKAGE MARKING**



#### Notes

- Only options 1 and 7 reflected in the package marking
- The VDE logo is only marked on option 1 parts
- · Tape and reel suffix (T) is not part of the package marking

## **Legal Disclaimer Notice**



Vishay

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